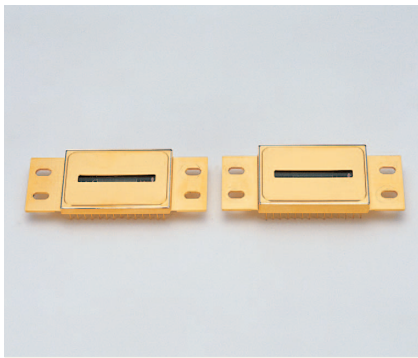


# InGaAs linear image sensors

G9201 to G9204 series



## Image sensor for DWDM wavelength monitor

The G9201 to G9204 series are InGaAs linear image sensors designed for WDM monitor detectors in optical communications. These linear image sensors contain a CMOS charge amplifier array, a CDS circuit, an offset compensation circuit, a shift register and a timing generator, along with an InGaAs photodiode array, and deliver high sensitivity and stable operation in the near infrared range. The package is hermetically sealed for high reliability and the light input window has an anti-reflective coating to improve the light detection efficiency.

The signal processing circuit on the CMOS chip allows selecting two conversion efficiencies (CE) by external voltage. A wide dynamic range can be obtained when the image sensor is operated at CE=16 nV/e<sup>-</sup>, while a high gain can be obtained at CE=320 nV/e<sup>-</sup>.

### Features

- Wide dynamic range
- Low noise and low dark current
- Two selectable conversion efficiencies
- Anti-saturation circuit
- CDS circuit\*<sup>1</sup>
- Offset compensation circuit
- Simple operation (by built-in timing generator \*<sup>2</sup>)
- High resolution: 25 μm pitch (512 ch)
- Low crosstalk
- 256 ch: 1 video line  
512 ch: 2 video lines

### Applications

- DWDM wavelength monitor
- Optical spectrum analyzer

### Options

- InGaAs multichannel detector head C8061-01\*<sup>3</sup>
- Multichannel detector head controller C7557-01\*<sup>3</sup>

\*1: A major source of noise in charge amplifiers is the reset noise generated when the integration capacitance is reset. A CDS circuit greatly reduces this reset noise by holding the signal immediately after reset to find the noise differential.

\*2: In conventional image sensor operation, external PLD (programmable logic device), etc. is used to input the required timing signals. However, the G9201 to G9204 series image sensors internally generate all timing signals on the CMOS chip just by supplying CLK and RESET pulses. This makes it simple to set the timings.

\*3: The G9203-256D and G9204-512D are not available for the C7557-01.

### Selection guide

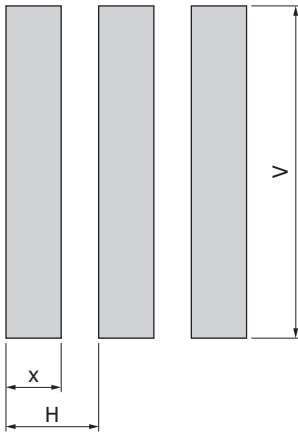
| Type no.                 | Cooling             | Image size (mm) | Number of total pixels | Number of effective pixels | Spectral response range (μm) | Defective pixels | Applicable multichannel detector head |
|--------------------------|---------------------|-----------------|------------------------|----------------------------|------------------------------|------------------|---------------------------------------|
| G9201-256S               | One-stage TE-cooled | 12.8 × 0.25     | 256                    | 256                        | 0.9 to 1.67 (-10 °C)         | 0                | C8061-01                              |
| G9202-512S               | One-stage TE-cooled |                 | 512                    | 512                        | 0.9 to 1.67 (-10 °C)         |                  | C8061-01                              |
| G9203-256D* <sup>4</sup> | Non-cooled          | 12.8 × 0.50     | 256                    | 256                        | 0.9 to 1.7 (25 °C)           |                  | -                                     |
| G9203-256S               | One-stage TE-cooled |                 | 256                    | 256                        | 0.9 to 1.67 (-10 °C)         |                  | C8061-01                              |
| G9204-512D* <sup>4</sup> | Non-cooled          |                 | 512                    | 512                        | 0.9 to 1.7 (25 °C)           |                  | -                                     |
| G9204-512S               | One-stage TE-cooled |                 | 512                    | 512                        | 0.9 to 1.67 (-10 °C)         |                  | C8061-01                              |

**Structure**

| Type no.     | Pixel size<br>[ $\mu\text{m}$ (H) $\times$ $\mu\text{m}$ (V)] | Pixel pitch<br>( $\mu\text{m}$ ) | Package  | Window material                                    |
|--------------|---|----------------------------------|--|--|
| G9201-256S   | 50 $\times$ 250   | 50                               | 28-pin metal<br>(refer to the dimensional outline) | Sapphire glass with<br>anti-reflective coating     |
| G9202-512S   | 25 $\times$ 250   | 25                               |  |  |
| G9203-256D*4 | 50 $\times$ 500   | 50                               | 22-pin ceramic                                     | Borosilicate glass with<br>anti-reflective coating |
| G9203-256S   |   |                                  | 28-pin metal<br>(refer to the dimensional outline) | Sapphire glass with<br>anti-reflective coating     |
| G9204-512D*4 | 25 $\times$ 500   | 25                               | 22-pin ceramic                                     | Borosilicate glass with<br>anti-reflective coating |
| G9204-512S   |   |                                  | 28-pin metal<br>(refer to the dimensional outline) | Sapphire glass with<br>anti-reflective coating     |

\*4: For the G9203-256D and G9204-512D specifications, see the separate datasheet available from HAMAMATSU.

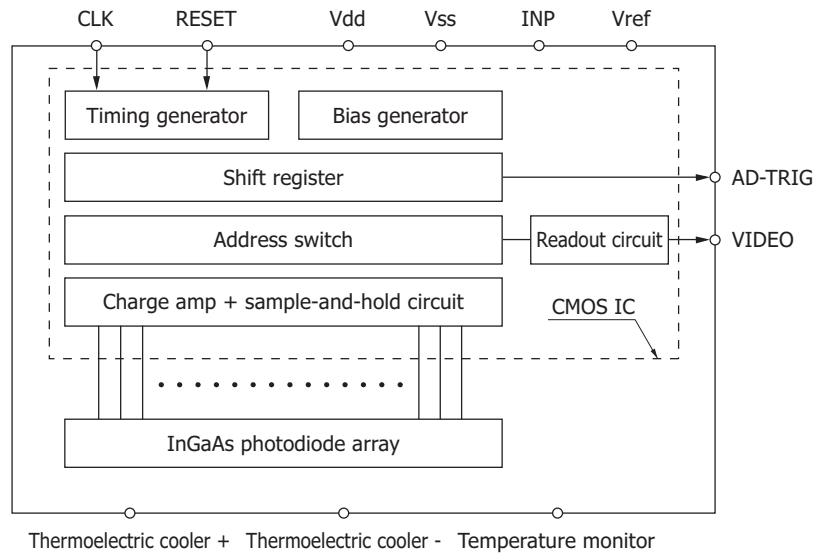
**Details of photosensitive area (unit: mm)**



| Number of pixels | x  | H  | V   |
|------------------|----|----|-----|
| 256              | 30 | 50 | 250 |
|                  |    |    | 500 |
| 512              | 10 | 25 | 250 |
|                  |    |    | 500 |

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**Block diagram**



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**Absolute maximum ratings**

| Parameter                       | Symbol         | Condition  | Min. | Max. | Unit |
|---------------------------------|----------------|--|------|------|------|
| Operating temperature           | Topr           | Chip and package temperature,<br>No dew condensation*5 | -40  | +70  | °C   |
| Storage temperature             | Tstg           | Chip and package temperature,<br>No dew condensation*5 | -40  | +85  | °C   |
| Supply voltage                  | Vdd, INP, Vref | Ta=25 °C   | -0.3 | +6   | V    |
| Clock pulse voltage             | V $\phi$       | Ta=25 °C   | -0.3 | +6   | V    |
| Reset pulse voltage             | V(RES)         | Ta=25 °C   | -0.3 | +6   | V    |
| Gain selection terminal voltage | Vcsel          | Ta=25 °C   | -0.3 | +6   | V    |

\*5: When there is a temperature difference between a product and the surrounding area in high humidity environment, dew condensation may occur on the product surface. Dew condensation on the product may cause deterioration in characteristics and reliability.

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

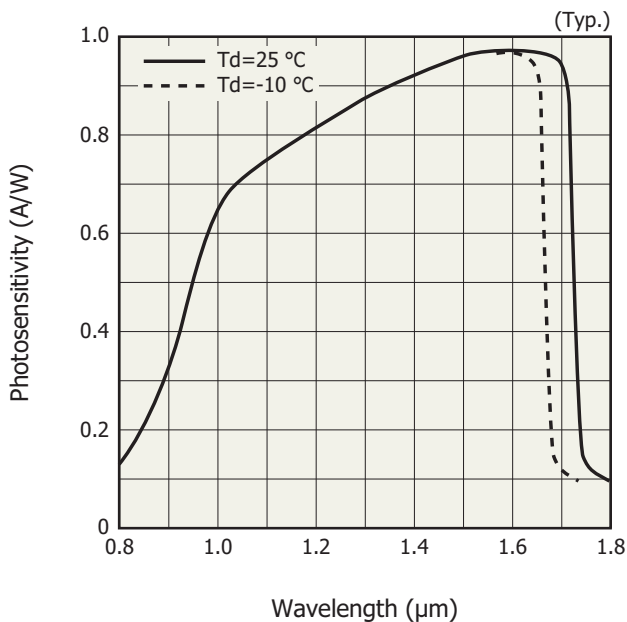
**Recommended terminal voltage**

| Parameter           | Symbol   | Min.      | Typ. | Max.      | Unit |
|---------------------|----------|-----------|------|-----------|------|
| Supply voltage      | Vdd      | 4.9       | 5.0  | 5.1       | V    |
|                     | Vref     | -         | 1.26 | -         | V    |
| Element bias        | INP      | 3.5       | 4.5  | 4.6       | V    |
| Ground              | Vss      | -         | 0    | -         | V    |
| Clock pulse voltage | V $\phi$ | Vdd - 0.5 | Vdd  | Vdd + 0.5 | V    |
|                     |          | 0         | 0    | 0.4       |      |
| Reset pulse voltage | V(RES)   | Vdd - 0.5 | Vdd  | Vdd + 0.5 | V    |
|                     |          | 0         | 0    | 0.4       |      |

**Electrical characteristics (Ta=25 °C)**

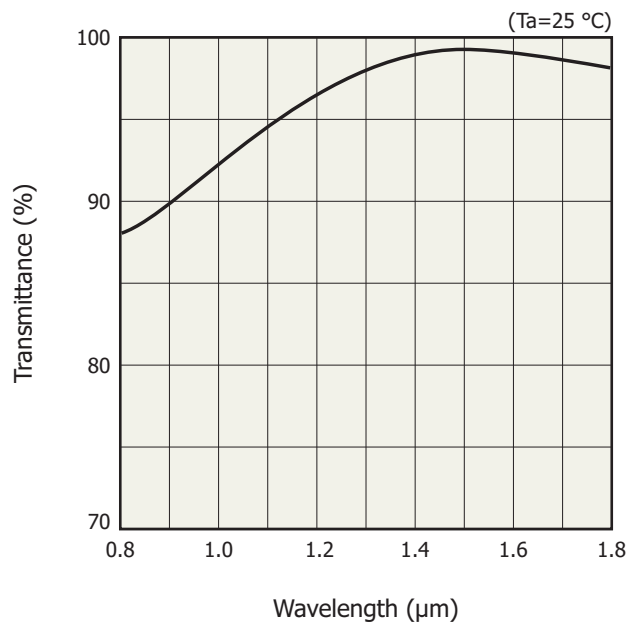
| Parameter             | Symbol  | Min.       | Typ. | Max. | Unit |
|-----------------------|---------|------------|------|------|------|
| Consumption current   | I(Vdd)  | 256 pixels | 45   | 50   | mA   |
|                       |         | 512 pixels | 90   | 100  |      |
|                       | I(Vref) | -          | -    | 1    | mA   |
|                       | I(INP)  | -          | -    | 1    | mA   |
| Clock frequency       | f       | 0.1        | -    | 4    | MHz  |
| Video data rate       | fV      | 0.0125     | f/8  | 0.5  | MHz  |
| Video output voltage  | High    | VH         | -    | INP  | V    |
|                       | Low     | VL         | Vref | -    | V    |
| Output offset voltage | Vos     | -          | Vref | -    | V    |
| A/D trigger voltage   | High    | VtrigH     | -    | Vdd  | V    |
|                       | Low     | VtrigL     | -    | GND  | V    |

**Spectral response**



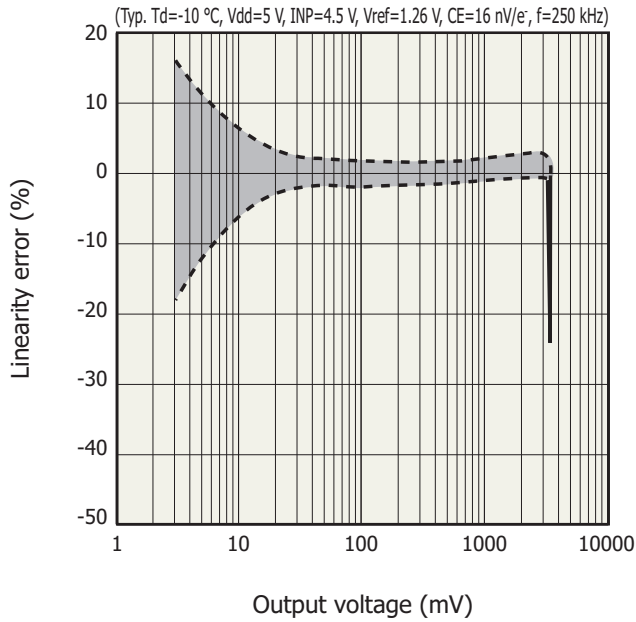
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**Spectral transmittance characteristic of window material (typical example)**



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### Linearity error (G9203-256S)



### Electrical and optical characteristics (Td=25 °C)

| Parameter                         | Symbol      | Condition                                | Min.  | Typ.  | Max. | Unit              |
|-----------------------------------|-------------|--|-------|-------|------|-------------------|
| Peak sensitivity wavelength       | $\lambda_p$ |  | -     | 1.55  | -    | $\mu\text{m}$     |
| Photosensitivity                  | S           | $\lambda = \lambda_p$                    | 0.85  | 0.95  | -    | A/W               |
| Conversion efficiency             | CE          | Cf=10pF                                  | -     | 16    | -    | nV/e <sup>-</sup> |
| Saturation voltage                | Vsat        |  | 3.0   | 3.2   | -    | V                 |
| Saturation charge                 | Qsat        | *6                                       | 30    | 32    | -    | pC                |
| Photoresponse nonuniformity       | PRNU        | *7                                       | -     | ±2    | ±5   | %                 |
| RMS noise voltage (readout noise) | N           | Standard deviation, Integration count=50 | -     | 180   | 300  | $\mu\text{V rms}$ |
| Dynamic range                     | D           | *6                                       | 10000 | 17777 | -    | -                 |
| Defective pixels*8                | -           |  | -     | -     | 0    | %                 |

\*6:  $V_{\phi} = 5 \text{ V}$ , CE=16 nV/e<sup>-</sup>

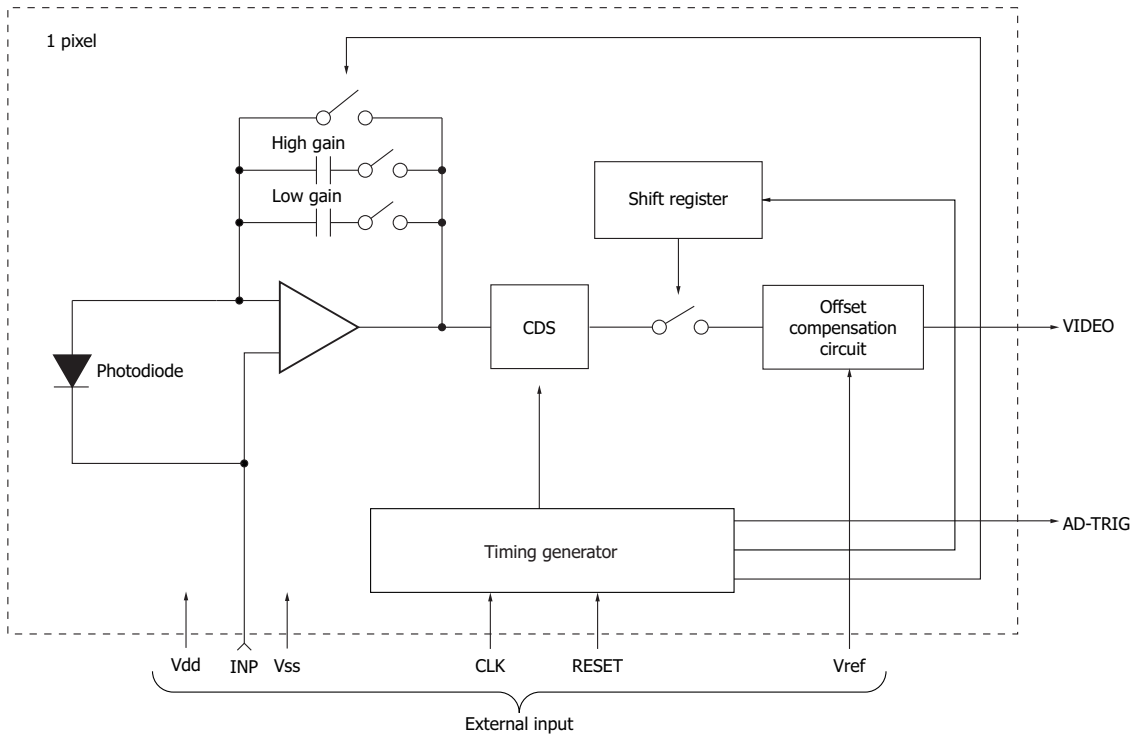
\*7: 50 % of saturation, integration time=10 ms, after dark output subtraction, excluding first and last pixels

\*8: Pixels with photoresponse nonuniformity, readout noise or dark current higher than the maximum value

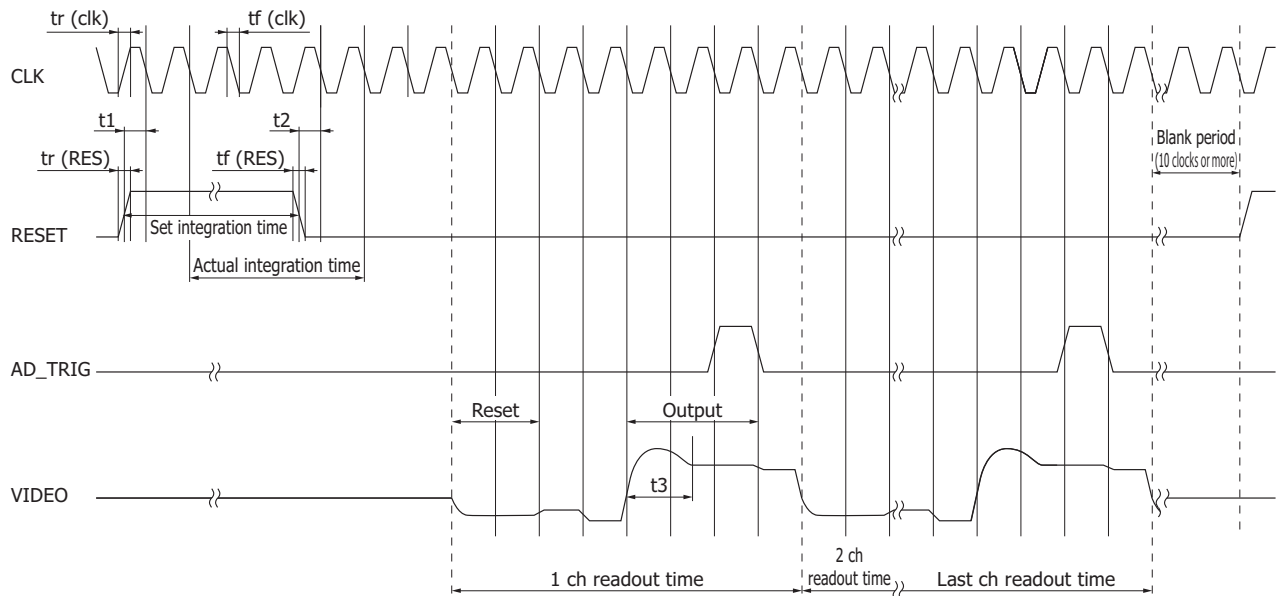
### Dark output characteristics (Td=25 °C, CE=16 nV/e<sup>-</sup>)

| Parameter                                  | Symbol     | Min. | Typ. | Max. | Unit |
|--|------------|------|------|------|------|
| Dark output<br>(dark output nonuniformity) | G9201-256S | -1   | 0.2  | 1    | V/s  |
|  | G9202-512S | -0.5 | 0.1  | 0.5  |      |
|  | G9203-256S | -2   | 0.4  | 2    |      |
|  | G9204-512S | -0.5 | 0.1  | 0.5  |      |
| Dark current                               | G9201-256S | -10  | 2    | 10   | pA   |
|  | G9202-512S | -5   | 1    | 5    |      |
|  | G9203-256S | -20  | 4    | 20   |      |
|  | G9204-512S | -5   | 1    | 5    |      |

**Equivalent circuit**

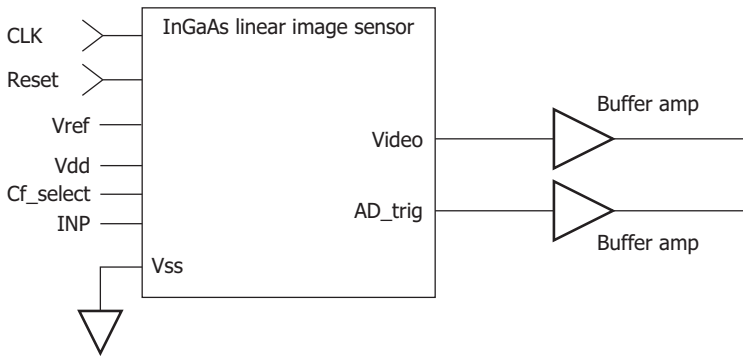


**Timing chart**



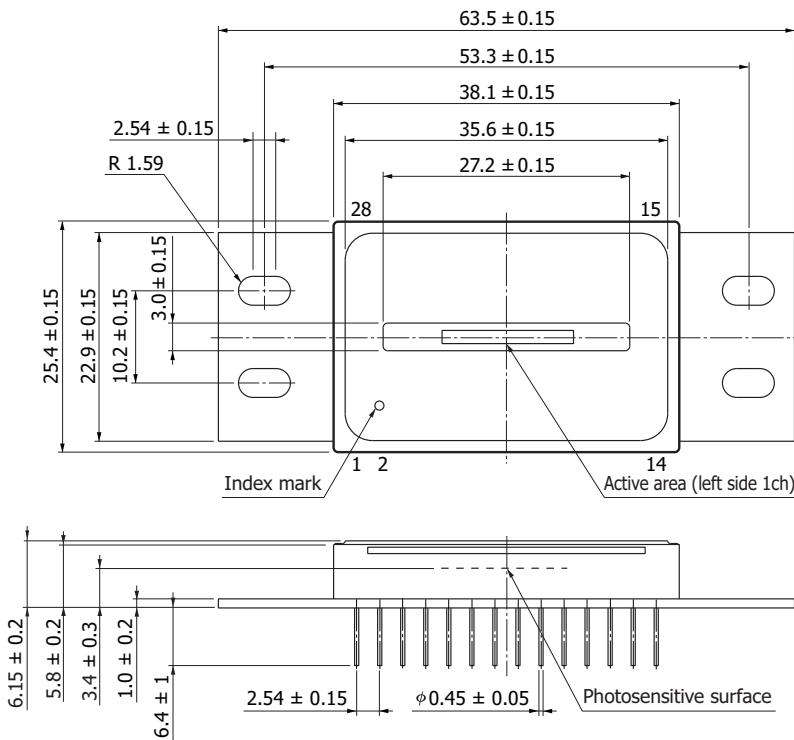
| Parameter                   | Symbol             | Min. | Typ. | Max. | Unit |
|-----------------------------|--------------------|------|------|------|------|
| Clock pulse frequency       | -                  | 0.1  | -    | 4    | MHz  |
| Clock pulse width           | tpw (clk)          | 100  | -    | -    | ns   |
| Clock pulse rise/fall times | tr (clk), tf (clk) | 0    | 20   | 100  | ns   |
| Reset pulse width           | tpw (RES)          | 6000 | -    | -    | ns   |
| Reset pulse rise/fall times | tr (RES), tf (RES) | 0    | 20   | 100  | ns   |
| Reset (rise) timing         | t1                 | 50   | -    | -    | ns   |
| Reset (fall) timing         | t2                 | 50   | -    | -    | ns   |
| Output settling time        | t3                 | -    | -    | 600  | ns   |

**Basic circuit connection**



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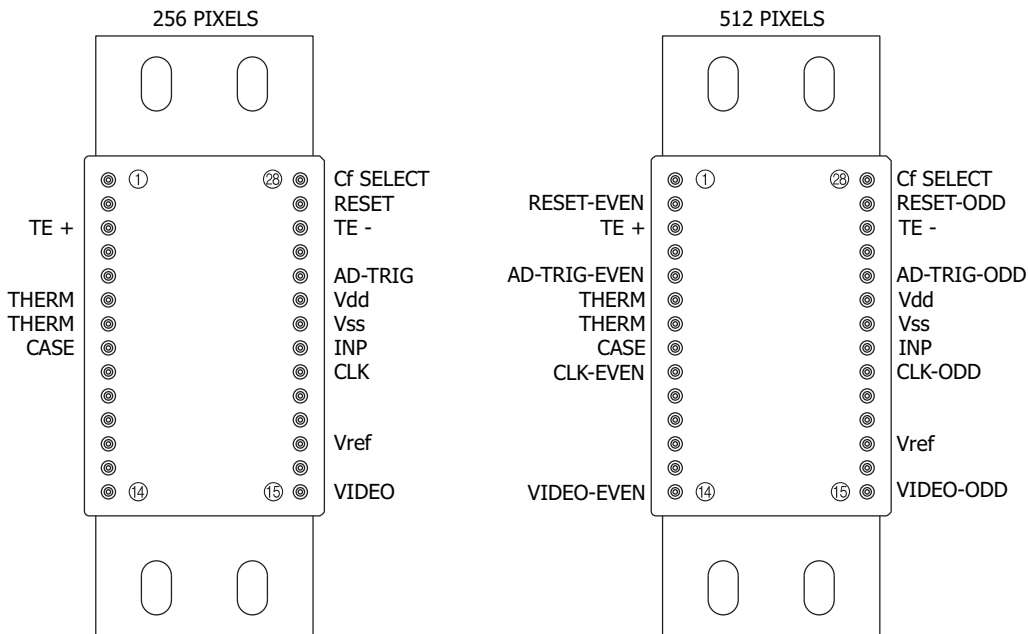
**Dimensional outline (unit: mm)**



Center accuracy of active area:  
 ±0.3 mm or less (with package center as reference point)  
 Rotation accuracy of active area:  
 ±2° or less (with package center as reference point)  
 Chip material: InGaAs  
 Package material: FeNi alloy  
 Lead treatment: Ni/Au plating  
 Lead material: FeNiCo alloy  
 Window material: sapphire  
 Refractive index of window material: n=1.76  
 Window material thickness: 0.66 mm  
 AR coat: coated (1.55 μm peak)  
 Window sealing method: brazing  
 Cap sealing: welding

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**Pin connections (top view)**



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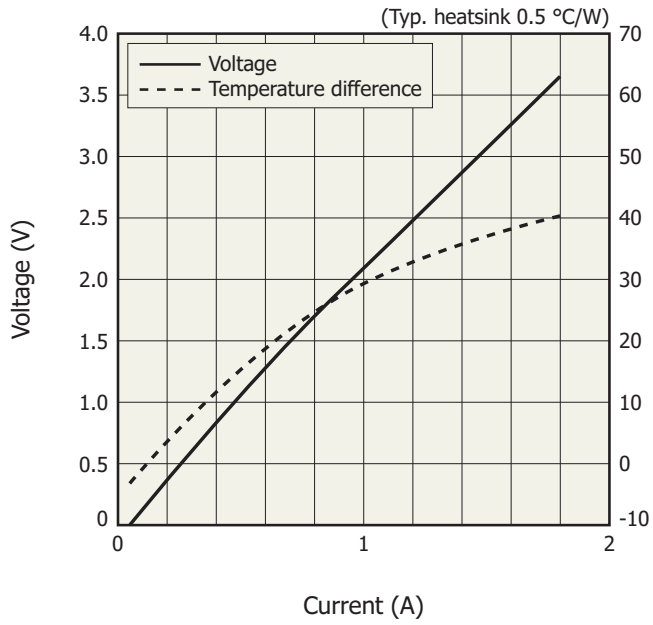
| Terminal name | Input/Output                  | Function and recommended connection   |
|---------------|-------------------------------|---|
| CLK           | Input (CMOS logic compatible) | Clock pulse for operating the CMOS shift register   |
| RESET         | Input (CMOS logic compatible) | Reset pulse for initializing the feedback capacitance in the charge amplifier formed on the CMOS chip. The width of the reset pulse is integration time.              |
| Vdd           | Input                         | Supply voltage for operating the signal processing circuit on the CMOS chip   |
| Vss           | -                             | Ground for the signal processing circuit on the CMOS chip   |
| INP           | Input                         | Reset voltage for the charge amplifier array on the CMOS chip   |
| Cf SELECT     | Input                         | Voltage that determines the feedback capacitance (Cf) on the CMOS chip. Low gain (CE=16 nV/e <sup>-</sup> ) at 0 V, and high gain (CE=320 nV/e <sup>-</sup> ) at 5 V. |
| CASE          | -                             | This terminal is electrically connected to the package.   |
| THERM         | Output                        | Thermistor terminal for monitoring temperature inside the package   |
| TE+, TE-      | Input                         | Power supply terminal for the thermoelectric cooler that cools the photodiode array   |
| AD-TRIG       | Output                        | Digital signal for A/D conversion; positive polarity  |
| VIDEO         | Output                        | Analog video signal; positive polarity  |
| Vref          | Input                         | Reset voltage for the offset compensation circuit on the CMOS chip  |

**Specifications of one-stage TE-cooler (Ta=25 °C, Vdd=5 V, INP=4.5 V)**

| Parameter                    | Condition | Symbol  | Min. | Typ. | Max. | Unit |
|------------------------------|-----------|---------|------|------|------|------|
| TE-cooler allowable current  |           | Ic Max. | -    | -    | 1.8  | A    |
| TE-cooler allowable voltage  |           | Vc Max. | -    | -    | 5.0  | V    |
| Temperature difference *8    | Ic=1.4 A  | Δt      | 40   | -    | -    | °C   |
| Thermistor resistance        |           | Rth     | 4.85 | 5.00 | 5.15 | kΩ   |
| Thermistor power dissipation |           | Pth     | -    | -    | 0.2  | mW   |

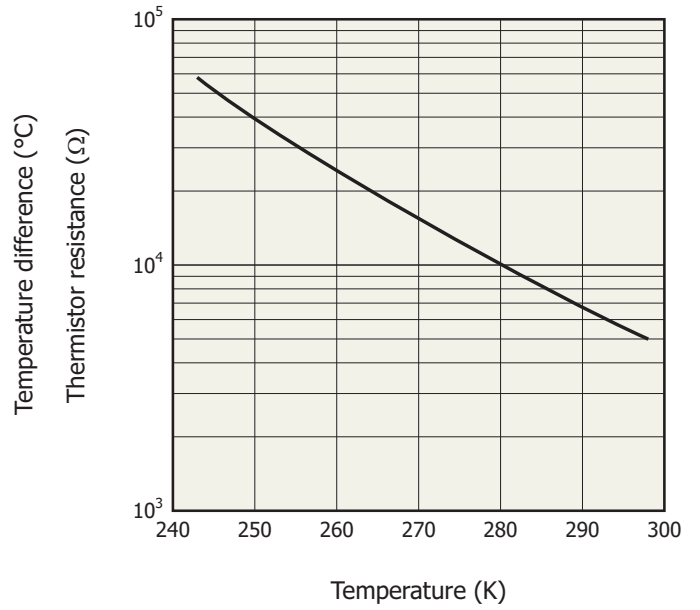
\*8: This is a temperature difference between the surface of active area and the heat radiating portion of package.

❑ One-stage TE-cooler temperature characteristic



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❑ Thermistor temperature characteristic



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A relation between the thermistor resistance and absolute temperature is expressed by the following equation.

$$R1 = R2 \times \exp B (1/T1 - 1/T2)$$

R1: Resistance at T1 [K]

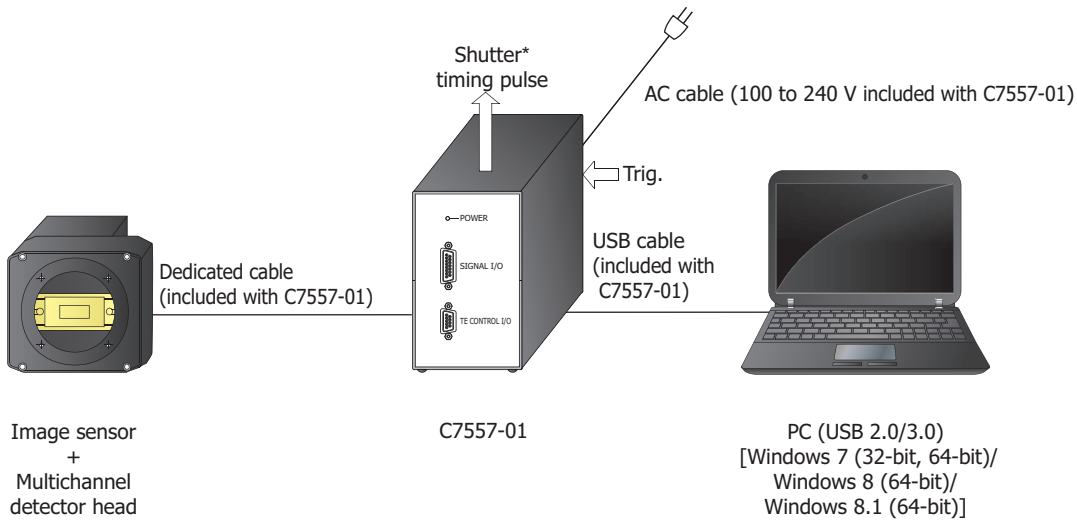
R2: Resistance at T2 [K]

B : B constant (B=3200 K ± 2%)

Thermistor resistance = 5 kΩ ± 3% (298 K)



## Connection of related products



\* Shutter, etc. are not available.

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## Electrostatic countermeasures

This device has a built-in protection circuit against static electrical charges. However, to prevent destroying the device with electrostatic charges, take countermeasures such as grounding yourself, the workbench and tools to prevent static discharges. Also protect this device from surge voltages which might be caused by peripheral equipment.

## Related information

[www.hamamatsu.com/sp/ssd/doc\\_en.html](http://www.hamamatsu.com/sp/ssd/doc_en.html)

- Precautions
- Disclaimer
- Image sensors

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